

No.1042F

LB1211 Series

General-Purpose Transistor Array

The LB1211 series are general-purpose transistor arrays containing 7 channels (5 channels: LB1217 only). They are especially suited for driving LEDs, lamps, small-sized relays, etc. The transistors can be standardized.

Features

· Common-emitter 7 channels.	LB1211.1212.1213.1214
· Common-emitter / channels.	LD1211,1212,1213,1214

· Common-collector 7 channels. LB1215,1216

· Independent 5 channels LB1217

Built-in base current limiting resistors. LB1212,1213,1214,1216

· Built-in Zener diodes for level shift. LB1212

· Capable of being direct driven with TTL, CMOS, PMOS, etc.

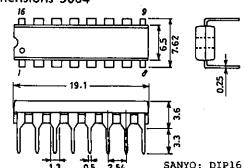
· Wide operating voltage and temperature ranges

Absolute Maximum Ratings at	Ta = 25°C			unit
Output Supply Voltage	V_{OUT}	LB1212/13/14 only	-0.5 to +50	V
Collector to Emitter Voltage	V_{CEO}	LB1211/15/16/17 only	35	V
Collector to Base Voltage	V_{CBO}	LB1211/15/16/17 only	50	V
Output Current	I_{OUT}		200	mA
Input Voltage	$V_{IN}1$	LB1212/13/14 only	-0.5 to +30	V
-	$V_{IN}2$	LB1216 only	-0.5 to +45	V
Input Current	I_{IN}	LB1211/15/17 only	25	mA
GND Pin Current	I_{GND}	·	500	mA
Allowable Power Dissipation	Pd max		960	mW
Operating Temperature	Topr		-20 to +75	$^{\circ}\mathrm{C}$
Storage Temperature	Tstg		-40 to +150	$^{\circ}\mathrm{C}$

Electrical Characteristics at Ta = 25°C		min	typ	max	unit	
Output Voltage	$ m V_{OUT}$ 1	$I_{IN} = 1 \text{mA}, I_{OUT} = 10 \text{mA}$		• •	0.2	V
	$V_{OUT}2$	I _{IN} =2mA,I _{OUT} =100mA LB1212/13/14 only			0.8	V
	V _{OUT} 3	I _{IN} =3mA,I _{OUT} =100mA LB1211/15/16/17 only			8.0	V
Output Leakage Current	I_{OFF}	$V_{\rm IN} = 0 V$, $V_{\rm OUT} = 25 V$			10	μΑ
Output Sustain Voltage	V _{OUT} (sus)	I _{OUT} =100mA	35			V
DC Current Gain	$h_{FE}1$	V _{OUT} =10V,I _{OUT} =10mA LB1212/13/14 only	50		500	
	$h_{ extbf{FE}}2$	V _{OUT} =10V,I _{OUT} =10mA LB1211/15/16/17 only	70		500	

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Package Dimensions 3064 (unit: mm) 6 _____

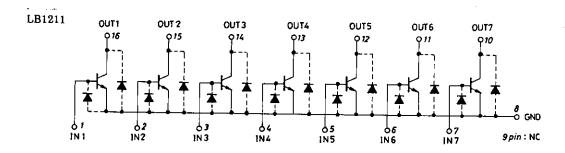


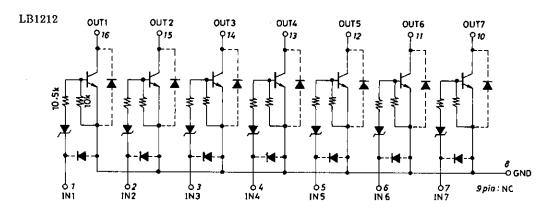
SANYO Electric Co., Ltd. Semiconductor Business Headquarters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

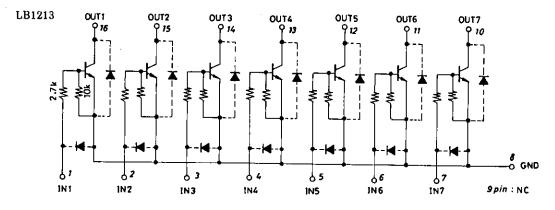
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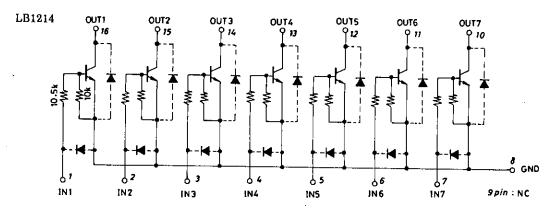
Input Voltage	$V_{\rm IN(on)}$	I _{IN} =1mA,I _{OUT} =10mA LB1211/15/16/17 only	min 0.4	typ	max	unit V
Turn-ON Time Turn-OFF Time	t _{ON} t _{OFF}	Refer to Test Circuit. Refer to Test Circuit.		50 200		ns ns

Equivalent Circuit

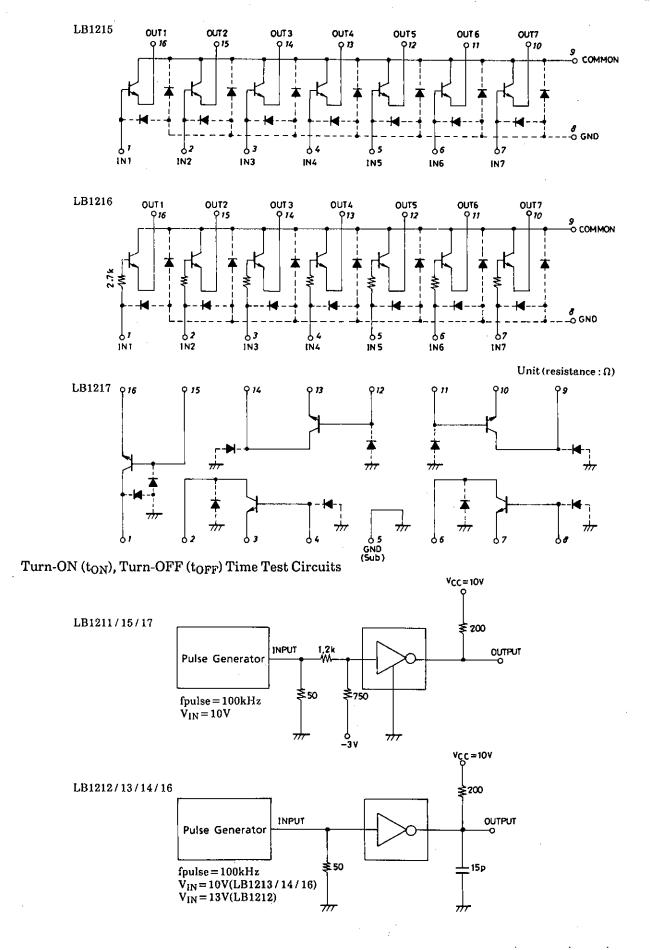






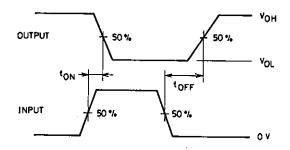


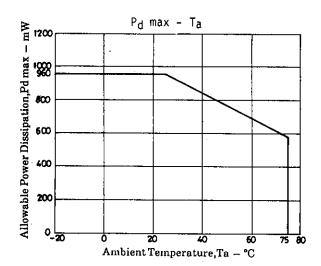
Unit (resistance : Ω)



Unit (resistance: Ω , capacitance: F)

Input/Output Waveforms





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